## NSN 5961-01-033-9370

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-033-9370 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 140.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 3.50 amperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 97525-123652 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**